



### **Product Summary**

BV <sub>DSS</sub>	RDS(on)	ID TA = +25°C
001/	125mΩ @ V <sub>GS</sub> = -10V	-4.3A
-60V	190mΩ @ V <sub>GS</sub> = -4.5V	-3.5A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor Control
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply

### 60V P-CHANNEL ENHANCEMENT MODE MOSFET

### **Features and Benefits**

- Fast Switching Speed
- Low Gate Drive
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
  For automotive applications requiring specific change
- control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

• This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An Automotive-Compliant Part is Available Under Separate Datasheet (ZXMP6A17GQ)

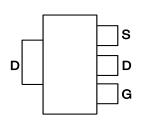
## **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
  Solderable per MIL-STD-202, Method 208 3
- Weight: 0.112 grams (Approximate)

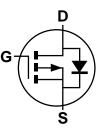


SOT223 (Type DN)





Pin Out - Top View



Equivalent Circuit

#### Ordering Information (Note 4)

Part Number	Case	Packaging
ZXMP6A17GTA	SOT223 (Type DN)	1,000/Tape & Reel
ZXMP6A17GTC	SOT223 (Type DN)	4,000/ Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

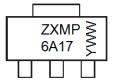
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**

SOT223 (Type DN)



 $\begin{array}{l} \text{ZXMP6A17} = \text{Product Type Marking Code} \\ \text{YWW} = \text{Date Code Marking} \\ \text{Y or } \overrightarrow{\text{Y}} = \underbrace{\text{Year (ex: 1 = 2021)}} \\ \text{WW or } \overrightarrow{\text{WW}} = \text{Week (01 to 53)} \end{array}$ 

#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		Vdss	-60	V	
Gate-Source Voltage		Vgss	±20	V	
		(Note 6)		-4.3	
Continuous Drain Current	Vgs = 10V	T <sub>A</sub> = +70°C (Note 6)	ID	-3.5	А
		(Note 5)	-	-3.0	
Pulsed Drain Current	$V_{GS} = 10V$	(Note 7)	I <sub>DM</sub>	-13.7	А
Continuous Source Current	(Body Diode)	(Note 6)	ls	-4.3	А
Pulsed Source Current (Bod	y Diode)	(Note 7)	I <sub>SM</sub>	-13.7	А

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	5	2.0 16	W	
Linear Derating Factor	(Note 6)	— P <sub>D</sub>	3.9 31	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 5)	<b>D</b>	62.5	°C/W	
	(Note 6)	R <sub>0JA</sub>	32.0		
Thermal Resistance, Junction to Lead	(Note 8)	Rejl	9.8		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Notes: 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

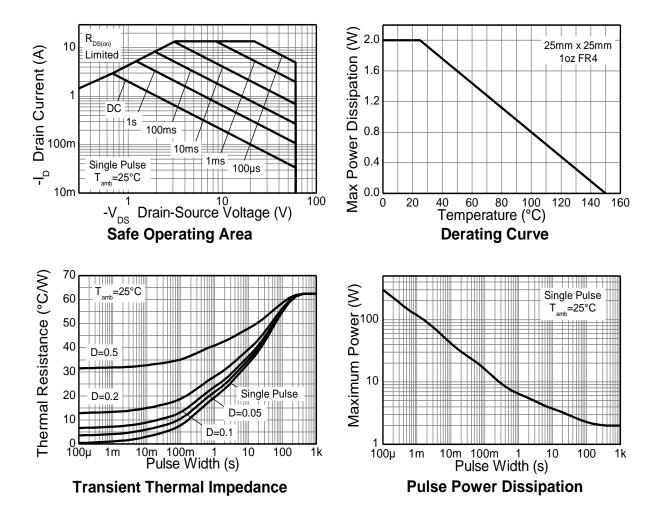
6. Same as Note 5, except the device is measured at t  $\leq$  10sec.

7. Same as Note 5, except the device is pulsed with D = 0.02 and pulse width  $300\mu$ s. The pulse current is limited by the maximum junction temperature.

8. Thermal resistance from junction to solder-point (at the end of the drain lead).



# **Thermal Characteristics**





Notes:

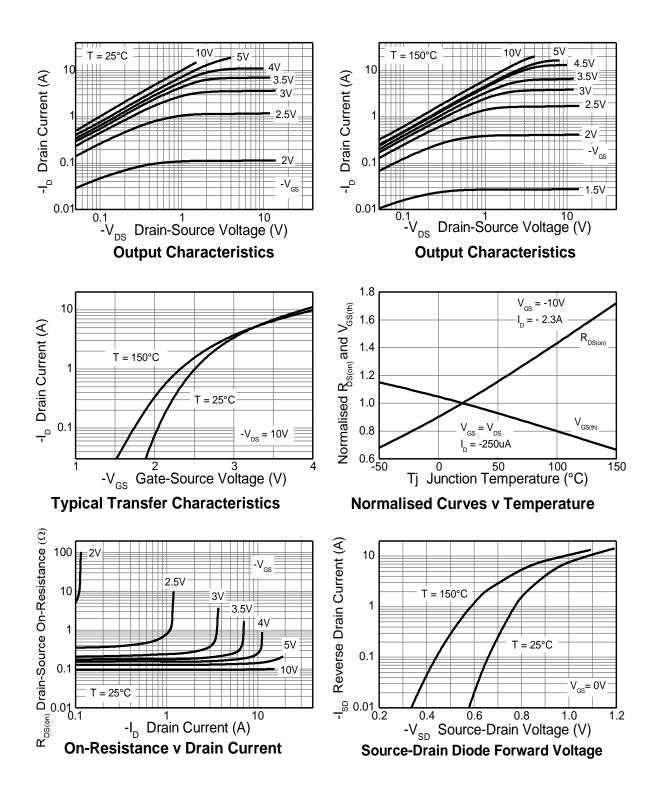
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test	Condition	
OFF CHARACTERISTICS			•	•	•			
Drain-Source Breakdown Voltage	BVDSS	-60			V	I <sub>D</sub> = -250µA, V <sub>GS</sub> = 0V		
Zero Gate Voltage Drain Current	IDSS	_	_	-0.5	μA	V <sub>DS</sub> = -60V, V	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$		
ON CHARACTERISTICS								
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.0	_	—	V	$I_{D} = -250 \mu A$ , $V_{DS} = V_{GS}$		
Statia Drain Source On Basistones (Nate 0)	6		96	125		$V_{GS}$ = -10V, $I_D$	= -2.2A	
Static Drain-Source On-Resistance (Note 9)	RDS(ON)	—	120	190	mΩ	V <sub>GS</sub> = -4.5V, I <sub>E</sub>	) = -1.8A	
Forward Transconductance (Notes 9 & 10)	<b>g</b> fs	_	4.7	_	S	V <sub>DS</sub> = -15V, I <sub>D</sub> = -2.2A		
Diode Forward Voltage (Note 9)	Vsd	_	-0.85	-0.95	V	Is = -2.0A, V <sub>GS</sub> = 0V, T <sub>J</sub> = +25°C		
Reverse Recovery Time (Note 10)	t <sub>rr</sub>		25.1	_	ns	Is = -1.7A, di/dt = 100A/μs, T <sub>J</sub> = +25°C		
Reverse Recovery Charge (Note 10)	Qrr	_	27.2	_	nC			
DYNAMIC CHARACTERISTICS (Note 10)	·		•		•	•		
Input Capacitance	Ciss	_	637	_	pF	V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V - f = 1MHz		
Output Capacitance	Coss	_	70.0	_	pF			
Reverse Transfer Capacitance	Crss	_	53.0	—	pF			
Total Gate Charge (Note 11)	Qg	_	9.0	_	nC	Vgs = -4.5V		
Total Gate Charge (Note 11)	Qg	_	17.7	_	nC		Vps = -30V	
Gate-Source Charge (Note 11)	Q <sub>gs</sub>		1.6	_	nC	V <sub>GS</sub> = -10V I <sub>D</sub> = -2.2A		
Gate-Drain Charge (Note 11)	Q <sub>gd</sub>	_	4.4	_	nC			
Turn-On Delay Time (Note 11)	tD(on)	_	2.6	_	ns		•	
Turn-On Rise Time (Note 11)	tr	_	3.4		ns	$V_{DD} = -30V, V_{GS} = -10V$ $I_D = -1A, R_G \cong 6.0\Omega$		
Turn-Off Delay Time (Note 11)	t <sub>D(off)</sub>	_	26.2		ns			
Turn-Off Fall Time (Note 11)	t <sub>f</sub>		11.3	_	ns			

9. Measured under pulsed conditions. Pulse width  $\leq$  300µs; duty cycle  $\leq$  2%. 10. For design aid only, not subject to production testing. 11. Switching characteristics are independent of operating junction temperatures.



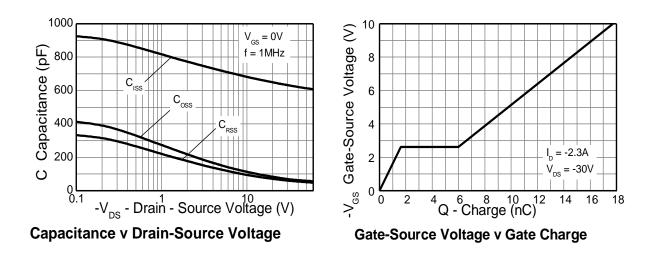
# **Typical Characteristics**



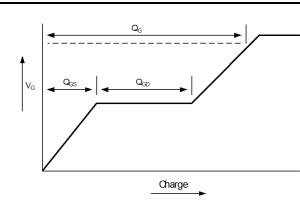


ZXMP6A17G

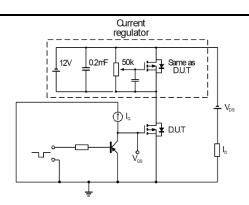
# Typical Characteristics (continued)



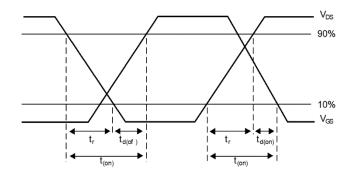
**Test Circuits** 



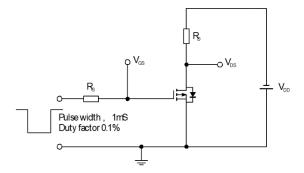
Basic gate charge waveform



Gate charge test circuit





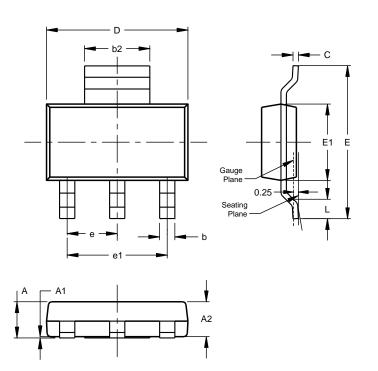


Switching time test circuit



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



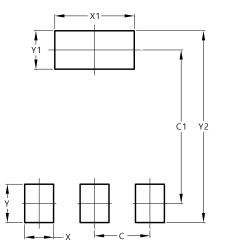
SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
c	0.20	0.32			
D	6.30	6.70			
ш	6.70	7.30			
E1	3.30	3.70			
e			2.30		
e1			4.60		
Ĺ	0.85				
All [	All Dimensions in mm				

#### SOT223 (Type DN)

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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